

UNIVERSITI PUTRA MALAYSIA

MICROSTRUCTURE AND DYNAMIC MAGNETIC PROPERTIES OF THALLIUM-BASED SUPERCONDUCTORS

ABDUL TALIB BIN SHAARI

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.

By

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Abstract of the thesis presented to the Senate of Universiti Putra Malaysia in fulfillment of the requirements for the degree of Master of Science

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Ac susceptibility study is one of the best methods in characterizing bulk superconductors. Four systems (A, B, C and D) of Thallium-based bulk superconductors were analyzed using this method. They were $A = (Tl_{0.85}Cr_{0.15}) Sr_2$ $(Ca_{1-x}Pr_x) Cu_2O_7$, $B = (Tl_{0.85}Cr_{0.15}) Sr_2 (Ca_{1-x}Nd_x) Cu_2O_7$, $C = (Tl_{0.85}Cr_{0.15}) Sr_2 (Ca_1,$ $xPr_x) Cu_2O_7$, and $D = (Tl_{0.85}Cr_{0.15}) Sr_2 (Sr_{1-x}Pr_x) Cu_2O_7$. The temperature dependent ac susceptibility curves and field dependent ac susceptibility curves were obtained using Lake Shore AC Susceptometer Model 7000. The dimensions of each sample were 2mmx2mmx10mm. Certain ranges of temperatures were identified from temperature dependent ac susceptibility curves for use in plotting the field dependent ac susceptibility curves for each sample. The applied fields (0.1 – 10 Oersted) were not high enough to observe the contributions from intragranular supercurrents. Therefore the data obtained were from the intergranular matrix. Bean's Model is used to explain the dynamic magnetic properties that resulted from the data T_c , T_p and T_{cj} that were obtained from temperature dependent ac susceptibility curves. I_0 was calculated from T_c and T_{cj} using the Ambegaokar-Baratoff formula and J_c (T) were



calculated from Bean's model. T_c and I_0 were plotted against the concentration x and $J_c(T)$ were plotted against temperature T.

From this research work the effect of doping in general reduced the T_c and I_0 values. For system D, the values fall gradually where as for the rest they fall very fast especially those of system B. These are reflected in the graphs of T_c versus x and I_0 versus x. The degree of compactness can be drawn as follows: D > C > A > B.

From $J_c(T)$ versus T, $J_c(T)$ values drop gradually for system D whereas for the other systems, $J_c(T)$ values drop very fast. All the $J_c(T)$ maximum values were increased as the field increased and these were attained at lower temperatures. At particular field, as the concentration increased, these were attained at lower temperatures also.

Kim's Model was used to explain the data obtained from field dependent ac susceptibility curves. It was found that systems D and C have certain range of temperatures where the curves follow Kim's Model. For example, these are reflected in the curves χ_m " (H_m) versus $-\chi_m$ ' (H_m) and χ_m " (H_m) versus logH_m at various temperatures and dopings for system D, x = 0.3, T = 59 K, J_c (H) = 2.66 X 10⁵ Am⁻², for system C, x = 0.2, T = 70 K, J_c (H) = 1.66 X 10⁵ Am⁻² and for system A, x = 0.2, T = 53 K, J_c (H) = 3.46 X 10⁵ Am⁻².

SEM photographs were also taken and analyzed. The microstructures of systems A and B are more flat and round in shape. They look porous and having bigger voids whereas those of systems D and C have long rectangular shape or rodliked in shape and look more compact and homogenous. The compactness and small voids probably lead to slow reduction of I_0 and T_c in systems D and C. Thus systems D and C are better connected than those of Systems A and B.

Thus the doping and heat treatment have certain effects on the dynamic magnetic properties of these superconductors as shown in the values of the critical current density J_c (T), J_c (H), I_0 and T_c . Further heating (1.5 hours), as in system A, did not strenghten the weak-links.

From the analysis of data obtained from temperature dependent ac susceptibility curves, analysis of the field dependent ac susceptibility curves and the analysis of the SEM photographs, system D, x = 0.3 is believed to have the best microstructure that give the dynamic magnetic properties which can be explained by the Bean's Model and Kim's Model.



Abstrak tesis yang dikemukakan kepada Senat Universiti Putra Malaysia bagi memenuhi keperluan ijazah Master Sains

PENYELIDIKAN MIKROSTRUKTUR DAN CIRI-CIRI DINAMIK KEMAGNETAN BAGI BAHAN SUPERKONDUCTOR BERASASKAN THALLIUM

Oleh

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Penyelidikan kerentanan au adalah salah satu cara yang terbaik untuk mengkaji ciri-ciri kemagnetan bahan superconduktor. Empat sistem superkonductor berasaskan Thallium (Sistem A, B, C and D) telah dikaji menggunakan teknik ini. Empat system itu ialah sebagai berikut: $A = (Tl_{0.85}Cr_{0.15}) Sr_2 (Ca_{1-x}Pr_x) Cu_2O_7$, $B = (Tl_{.85}Cr_{0.15}) Sr_2 (Ca_{1-x}Nd_x) Cu_2O_7$, $C = (Tl_{0.85}Cr_{0.15}) Sr_2 Ca_{1-x}Pr_x) Cu_2O_7$, $D = (Tl_{0.85}Cr_{0.15}) Sr_2 (Sr_1. xPr_x) Cu_2O_7$. Graf kerentanan au yang bergantung kepada suhu dan bergantung pada medan didapati menggunakan alat A.C. Susceptometer Model 7000. Julat suhu dipilih dari graf kerentanan au bergantung kepada suhu untuk digunakan melakar graf kerentanan au bergantung kepada medan. Dimensi sampel ialah 2mm x 2mm x 10mm. Mikrostruktur tiap sampel diambil dengan mengunakan alat SEM. Daripada graf kerentanan au bergantung pada medan, julat suhu yang mengikuti tuntutan model keadaan genting (Kim's Model) telah dipilih. Data yang akan didapati adalah dari matriks antaragranular. Model Bean digunakan untuk menganalisis data dari graf

kerentanan au bergantung pada suhu. I_0 dihasilkan dengan menggunakan formula Ambegaokar-Baratoff dengan menggunakan T_c dan T_{cj} yang didapati dari graf kerentanan au bergantung kepada suhu dan J_c (T) dikira dari Model Bean. Suhu T_c dan I_0 diplotkan melawan x dan J_c (T) diplotkan melawan suhu T.

Daripada penyelidikan ini akibat daripada pendopan, T_c dan I_0 telah menurun nilainya. Bagi sampel D nilai ini menurun dengan perlahan tetapi bagi sistem yang lain nilai ini menurun dengan cepat. Ini menunjukkan bahawa sistem D mempunyai mikrostruktur yang padat dari yang lain. Kepadatan itu boleh ditulis sebagai berikut: D > C > A > B.

Daripada Graf J_c (T) melawan T, J_c (T) menurun secara perlahan juga bagi sistem D. Sistem lain menurun dengan cepat terutama sistem B. Semua nilai maxima J_c (T) meningkat bila medan bertambah tetapi pada suhu rendah. Pada nilai medan tertentu, nilai J_c (T) bertambah bila x bertambah tetapi pada suhu rendah juga.

Model Kim digunakan untuk menganalisis data daripada graf bergantung pada medan. Juga didapati bahawa sistem D dan C mempunyai julat suhu lebih besar yang memenuhi tuntutan Model Kim. Ini bolehlah dilihat pada graf χ_m (H_m) melawan - χ_m

(H_m) dan graf χ_m " (H_m) melawan logH_m untuk sistem D, x = 0.3, T = 59 K, J_c(H) = 2.66 X 10⁵ Am⁻², untuk sistem C, x = 0.2, T = 70 K, J_c(H) = 1.66 X 10⁵ Am⁻² dan sistem A, x = 0.2, T = 53 K, J_c(H) = 3.46 X 10⁵ Am⁻².

Gambar SEM juga diambil bagi semua sampel dan dianalisis. Didapati mikrostruktur bagi sistem A dan B bulat, besar dan leper, tetapi bagi sistem D dan C condong kepada bentuk segiempat panjang dan kecil. Mikrostruktur sistem D dan C nampak lebih padat daripada sistem A dan B. Mungkin kepadatan ini menyebabkan nilai T_c dan nilai I_0 menurun lebih lambat berbanding dengan sistem A dan B.

Nampaknya pendopan ada kesan kepada nilai J_c (T), J_c (H), I_0 dan T_c tetapi pemanasan lebih (1.5 jam) tidak memberi kesan kepada nilai nilai ini terutama pada nilai I_0 .

Daripada analisis data daripada kerentanan au bergantung pada suhu dan yang bergantung pada medan dan analisis mikrostruktur dari gambar SEM, dibuat kesimpulan bahawa sistem D, x = 0.3 adalah sistem yang mempunyai mikrostruktur yang terbaik yang mempunyai ciri ciri kemagnetan dinamik yang boleh diterangkan dengan menggunakan Model Bean dan Model Kim.



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LIST OF ABBREVIATIONS

- T_c critical temperature of temperature dependent ac susceptibility curve
- T_p peak temperature of temperature dependent ac susceptibility curve
- T_{ci} phase lock temperature of temperature dependent ac susceptibility curve
- T_{po} peak temperature for x = 0
- T_{p1} peak temperature for x = 0.1
- T_{p2} peak temperature for x = 0.2
- T_{p3} peak temperature for x = 0.3
- T_{p4} peak temperature for x = 0.4
- J_c critical current density
- x doping concentration
- I_o maximum Josephson current
- E_j Josephson coupling energy
- H magnetic field
- H_I internal magnetic field
- H_m maximum external magnetic field
- H_p external penetration field
- B magnetic induction
- M magnetization
- M_I local magnetization
- HTS high temperature superconductors
- H_{ac} applied magnetic field
- m moment
- V Voltage
- χ_{ac} ac susceptibility

 μ_0 permeability of free space

a dimension of half of slab thickness	
---------------------------------------	--

- χ_m intergranular matrix component of imaginary ac susceptibility
- χ_m intergranular matrix component of real ac susceptibility
- χ " imaginary component of ac susceptibility
- χ ' real component of ac susceptibility
- fg volume fractions of superconducting grains
- M_g magnetization of superconducting grains
- M_m magnetization of intergranular matrix
- χ_g ac susceptibility of superconducting grains
- H_{c1} Lower critical magnetic field
- H_{c2} higher critical magnetic field
- H_{clg} lower critical magnetic field of grains
- k positive constant in Kim Model
- H₀ constant manetic field in Kim Model
- p constant in Kim Model
- f frequency
- c calibration coefficient
- θ temperature
- ρ resistivity
- YBCO Yattrium Barium Copper Oxide
- BSCCO Bismuth Strontium Cobalt Copper Oxide
- TBCCO Thallium Bismuth Cobalt Copper Oxide



CHAPTER I

GENERAL INTRODUCTION.

What is a superconductor? It is a material which exhibits two distinct properties, that is, zero resistivity: $\rho = 0$ for all T < T_c and zero magnetic induction: B = 0 inside the superconductor. The magnetic inductance becomes zero inside the superconductor when it is cooled below T_c in a weak external magnetic field. The magnetic flux is expelled from the interior of the superconductor. This effect is called the Meissner-Ochsenfeld effect after its discoverers.

In 1957, Alexei Abrikosov studied the behaviour of superconductors in an external magnetic field and found that there are two types of superconductors: Type-I and Type-II superconductors. Type-I expelled magnetic flux completely from their interior while Type-II do it completely only at small fields but partially at higher fields. Thanks to this property, i.e., the formation of the so-called mixed state, this Type-II can sustain superconductivity even in fields higher than 10 Tesla. Because of this, Type-II superconductors are of interest for most large-scale application.

In zero field cooled (ZFC) condition (See Figure 1.1), the superconductor is cooled first below T_c and when the field is applied below T_c , the field is excluded. This is called **magnetic shielding**. But in field cooled (FC) condition (See Figure 1.1) when constant field is applied before it is cooled below T_c and when it is cooled







Figure 1.1: Effect of zero field cooling (ZFC) and field cooling (FC) On a superconductor.

(Source: Superconductivity; Charles P. Poole, Jr, Academic Press, 1995)



High T_c Superconductors

High T_c superconductors belong to Type-II superconductors. Examples of high T_c superconductors are YBCO, BSCCO, TBCCO and finally HBCCO systems. The highest T_c for YBCO system belongs to YBCO (123) phase, that is, T_c = 92 K, while for BSCCO (2223), T_c = 110 K, and lastly for TBCCO (2223) and HBCCO (1223) T_c = 125 K and T_c = 153 K respectively. These High T_c superconductors are usually granular and since it is granular the problems of weak-links occur.

Thallium-Based High T_c Superconductors

Thallium-based system (Figure 1.2 and Table 1.1) was discovered by Z.Z.Sheng and A.M.Hermann (1988). TIBaCuO has $T_c = 81$ K and it rose to 100 K when Ca was included in the system and in 1993, TI-2223 was discovered with the highest $T_c = 125$ K (Table 1.1). Thallium-based systems are considered today as the most likely candidates for power applications such as transmission lines and various magnetic systems since they have low flux creep. The thallium single layer materials such as TI-1223 show less flux creep than the more anisotropic double layer such as Bi-2212, Bi-2223 and TI-2223. The insulator thickness, the spacing between the copper oxide layer blocks is an important parameter for flux creep. Among the materials of the TI-based group the best position of the irreversibility line belongs to this TI-1223 phase. It is accepted that stronger coupling between conducting Cu-O planes separated by single-layer insulating TI-O plane is responsible for the improved properties of this kind of material in higher magnetic fields. These types of applications requires J_c values in the range of 10^4 - 10^5 A cm⁻² which are